Evidence of nodes in the order parameter of the superconducting doped topological insulator $Nb_xBi₂Se₃$ via penetration depth measurements

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The low-temperature variation of the London penetration depth $\lambda(T)$ in the candidate topological superconductor $Nb_xBi₂Se₃$ ($x = 0.25$) is reported for several crystals. The measurements were carried out by means of a tunnel-diode oscillator technique in both field orientations ($H_{\text{rf}} \parallel c$ and $H_{\text{rf}} \parallel ab$ planes). All samples exhibited power-law behavior at low temperatures ($\Delta \lambda \sim T^2$) clearly indicating the presence of point nodes in the superconducting order parameter. The results presented here are consistent with a nematic odd-parity spin-triplet E_u pairing state in $Nb_xBi_2Se_3$.

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Topological insulators, predicted and realized in the past several years [\[1–4\]](#page-4-0), are materials that display new quantum states that arise from the topology of their electronic structure. In particular, gapless electronic surface and edge states arise, whereas the bulk electronic structure is gapped. Topological states have also been described for superconducting materials [\[5–8\]](#page-4-0) in which a superconducting bulk gap, complete or nodal [\[9\]](#page-4-0), coexists with gapless surface states [\[10–14\]](#page-4-0). Quasiparticle excitations of the surface states are considered Majorana fermions. Because the surface states of topological insulators and superconductors are topologically protected and thus robust against disorder, they have attracted considerable attention for possible use in spintronics or fault-tolerant quantum computing [\[15,16\]](#page-4-0).

The emergence of topological superconductivity depends sensitively on the material's symmetries: time-reversal symmetry, spin-rotation symmetry, inversion, and other crystal symmetries. For instance, in a time-reversal symmetric and inversion symmetric system, the topological nature of the superconducting state is determined by the shape of the Fermi surface and the symmetry of the order parameter. Specifically, odd-parity pairing, $\Delta(-\mathbf{k}) = -\Delta(\mathbf{k})$, and a Fermi surface containing an odd number of time-reversal invariant momenta, $\mathbf{k} = -\mathbf{k} + \mathbf{G}$ with **G** a reciprocal lattice vector, will yield a topological superconductor. In the case of weak spin-orbit coupling, odd-parity pairing corresponds to a spintriplet pairing. Thus, conventional *s*-wave superconductors are not topological and do not display Majorana surface states. However, the coupling of the electron wave vector to its spin through strong spin-orbit coupling can induce unconventional pairing symmetries in time-reversal symmetric systems [\[8,14,17\]](#page-4-0). In a recent extensive theoretical study [\[35\]](#page-4-0) of odd-parity superconductors in trigonal and hexagonal crystal systems it was found that strong spin-orbit coupling produces either a time-reversal breaking, rotational symmetry preserving chiral phase (analogous to the axial *p*-wave state) or a time-reversal symmetric but spin-rotational symmetry breaking nematic state, in which the nematic direction is given by the axis of zero total spin.

Because the requirements for realizing topological superconductors are similar to those for creating topological insulators, namely, strong spin-orbit coupling and electronic structures of specific symmetry, extensive work has been devoted to induce superconductivity in topological insulators by doping or applying pressure [\[5,18\]](#page-4-0). Among these, $Cu_xBi₂Se₃$ is the most studied [\[19–22\]](#page-4-0). An odd-parity, spintriplet pairing state has been proposed [\[14,23–25\]](#page-4-0), but not all data are consistent with this model. Point-contact spectroscopy measurements of this material show a zero-bias conductance peak [\[26–28\]](#page-4-0) indicating unconventional superconductivity, thermal transport measurements [\[29\]](#page-4-0) are not fully consistent with the BCS model for a fully gapped system, and anomalies in the dc magnetization [\[30\]](#page-4-0) indicate triplet pairing. Furthermore, no Pauli limiting effect is observed in upper critical field measurements [\[31\]](#page-4-0), also supporting odd-parity spin-triplet pairing. However, very low temperature (∼15 mK) scanning-tunneling microscopy (STM) measurements [\[32\]](#page-4-0) show a conventional, fully gapped BCS-like *s*-wave structure. Angular-dependent NMR [\[33\]](#page-4-0) and specific heat measurements [\[34\]](#page-4-0) reveal a two-fold in-plane anisotropy indicative of a nematic superconducting state [\[14,17,35\]](#page-4-0). Recently, superconductivity has been discovered in Nb-doped [\[36\]](#page-4-0) and Sr-doped $[37]$ Bi₂Se₃, with STM measurements $[38]$ finding a full gap in $Sr_xBi_2Se_3$, vestiges of which, however, persist up to almost double the bulk superconducting transition temperature. The emergence below T_c of a two-fold anisotropy in magnetotransport measurements on $Sr_xBi₂Se₃$ [\[39,40\]](#page-4-0) and in the in-plane magnetization of $Nb_xBi_2Se_3$ [\[41\]](#page-4-0) suggests the formation of a nematic state.

Here, we report on measurements of the low-temperature behavior of the superconducting penetration depth $\lambda(T)$ carried out in both field orientations ($H_{\text{rf}} \parallel c$ and $H_{\text{rf}} \parallel ab$ planes) in single crystals of Nb*x*Bi2Se3 with nominal composition of $x = 0.25$. The pairing symmetry is a key parameter in determining the topological state of the superconducting order which can be explored with $\lambda(T)$ measurements. We find clear evidence for point nodes in the superconducting gap in all crystals studied. In conjunction with reports on a 2-fold in-plane magnetic anisotropy [\[41\]](#page-4-0), our findings are consistent with a nodal topological superconducting state of *Eu* symmetry that preserves time-reversal symmetry and breaks spin-rotation symmetry, as has been proposed in the nematic superconductor model [\[14,35\]](#page-4-0). The critical field measurements yield a low

FIG. 1. (a) Crystal structure of $Nb_xBi₂Se₃$. The Nb atoms are intercalated between quintuple layers of Bi and Se [\[36\]](#page-4-0). Some unit cells will only have two Nb ions. (b) View along the *c* axis, showing an axis of mirror symmetry \hat{y} ; the nematic vector **n** lies along a direction perpendicular to the mirror axis. (c) Schematic of the superconducting gap structure in the E_u state, where the nodal axis lies along \hat{y} .

superconducting anisotropy of $\gamma \approx 2$, imposing constraints on the shape of the Fermi surface.

High-quality crystals of $Nb_xBi₂Se₃$ ($x = 0.25$) were grown by the same method used in Ref. [\[36\]](#page-4-0). The crystals show superconducting volume fractions approaching 100%. Nb_xBi₂Se₃ crystallizes [Figs. $1(a)$ and $1(b)$] into the same tetradymite space group $R\bar{3}m$ as the parent material $Bi₂Se₃$ with a slightly extended *c* axis due to incorporation of the Nb ion in the van der Waals gap between adjacent $Bi₂Se₃$ quintuple layers. Crystals cleave easily between quintuple layers and naturally yield flat surfaces parallel to *ab*.

Penetration depth measurements were carried out on crystals approximately $850 \times 700 \times 150 \ \mu m^3$ in size using a custom-built [\[42,43\]](#page-4-0) 14.5 MHz tunnel-diode oscillator (TDO). The samples were placed on a movable sapphire stage with temperature control from 0.4 to 30 K. With this technique, the change in the resonator frequency $\Delta f(T)$ is proportional to the change of the London penetration depth $\Delta\lambda$, $\Delta f(T)$ = $G \Delta \lambda(T)$, where the geometrical factor *G* depends on the sample shape and volume as well as the geometry of the resonator coil [\[44\]](#page-4-0). The magnitude of the magnetic rf field in the resonator coil used to sense changes in the penetration depth is ∼20 mG, ensuring that the sample remains fully in the Meissner state during measurements.

Figure 2 shows superconducting transitions of two $Nb_{0.25}Bi₂Se₃$ crystals as measured via the TDO technique with the rf field applied along the *c* direction of the crystals. Curves were offset for clarity. No secondary transitions indicating superconducting Nb $(T_c = 9.25 \text{ K})$ or NbSe₂ $(T_c \simeq 7.2 \text{ K})$ regions were observed at higher temperatures either via superconducting quantum interference device (SQUID) magnetometry or via TDO measurements.

To determine the superconducting anisotropy, the TDO frequency shift was measured on a rectangular, plate-like

FIG. 2. Temperature dependence of the normalized frequency shift in two select crystals of $Nb_xBi₂Se₃$ with nominal doping $x = 0.25$. One of the curves has been offset for clarity. The inset shows dc-SQUID magnetization curves versus field at temperatures from 1.8 K through T_c . The determination of the penetration field H_p marking the deviation from the Meissner line is indicated.

single crystal with dc fields (H_{dc}) applied both along the *c* axis as well as parallel to the *ab* plane. The results are presented in Fig. [3.](#page-2-0) The magnetic phase diagram shown in Fig. $3(c)$ was generated by determining the superconducting onset as the point where the TDO response had shifted 1 Hz below the normal state behavior. Field-dependent measurements on another crystal with the c axis perpendicular to H_{dc} were also performed, and the results of the two sets of measurements align. Extrapolations to zero temperature give the values $B_{c2\perp}$ (0 K) \approx 0.9 T and $B_{c2\parallel}$ (0 K) \approx 1.8 T. In-plane and out-of-plane coherence lengths of $\xi_{ab} \approx 19$ nm and $\xi_c \approx 9.5$ nm were estimated using the single-band Ginzburg-Landau relations $B_{c2\parallel} = \Phi_0 / (2\pi \xi_{ab}^2)$ and $B_{c2\perp} = \Phi_0 / (2\pi \xi_c \xi_{ab})$. Thus, $Nb_xBi₂Se₃$ is characterized by a rather low superconducting anisotropy of $\gamma \approx 2$, similar to reported values of 1.5 and 1.8 for the Sr-doped and Cu-doped materials, respectively [\[29,45\]](#page-4-0). This low B_{c2} anisotropy is indicative of an essentially three-dimensional electronic structure, consistent with recent quantum oscillation measurements on $Nb_xBi₂Se₃$ [\[46\]](#page-4-0).

The inset of Fig. 2 shows the field dependence of the dc magnetization measured at various temperatures in fields parallel to *c*. At low fields, the magnetization is linear in field as expected for the Meissner state. With increasing field, deviations from linearity arise at a field H_p , signaling the penetration of vortices. Since the sample is a plate with a rectangular cross section, effects due to the geometrical barrier arise for which the relation of H_p and H_{c1} is given as $H_p/H_{c1} = \tanh(\sqrt{\alpha t/w})$, where *t* and *w* are the thickness and width of the sample, and $\alpha = 0.67$ for a disk [\[47\]](#page-4-0). The inset in Fig. $3(c)$ summarizes the temperature dependence of H_{c1} and a fit according to the Ginzburg-Landau prescription $H_{c1}(T) =$ $H_{c1}(0)[1 - (T/T_c)^2]$ yielding $H_{c1}(0) \approx 75$ G. We note that this fit allows for a rough estimate of *λ*(0) which is otherwise difficult to obtain, but does not account for the precise temperature

FIG. 3. Field dependence of the TDO frequency shift $\Delta f(T)$ in a single crystal of $Nb_xBi₂Se₃$. (a) Suppression of T_c with the *c* axis parallel to H_{rf} . (b) Temperature dependence of the H_{c2} field from the TDO data for two orientations. Measurements on an additional crystal with c axis parallel to H_{rf} yield an identical phase curve (triangles). The inset shows H_{c1} values as extracted from dc-SQUID magnetization measurements.

variation of *λ* which depends on the order parameter symmetry and is described in detail below. Using the Ginzburg-Landau relation $H_{c1} = \Phi_0/(4\pi\lambda_{ab}^2)(\ln[\lambda_{ab}/\xi_{ab}] + 0.5)$ we estimate $\lambda(0) \approx 237$ nm and, with $\xi_{ab} \approx 19$ nm, a Ginzburg-Landau parameter of $\kappa \approx 12.5$, identifying Nb_xBi₂Se₃ as extreme type II. We note that since $\lambda(0)$ is rather large, the TDO measurements probe the gap symmetry in the bulk, not of a potential surface state.

The low-temperature variation of the penetration depth is determined by the distribution of the thermally excited quasiparticles on the Fermi surface and by electron scattering. A complete superconducting gap yields at sufficiently low temperatures an exponential variation of $\lambda(T)$, which in conventional BCS theory for an isotropic *s*-wave superconductor is given as

$$
\frac{\Delta\lambda(T)}{\lambda(0)} \approx \sqrt{\frac{\pi \Delta_0}{2T}} \exp\left(-\frac{\Delta_0}{T}\right),\tag{1}
$$

where Δ_0 is the zero temperature value of the energy gap. In contrast, gap nodes induce enhanced thermal excitation of quasiparticles, typically resulting in a power-law variation of *λ*: $\Delta\lambda \sim T^n$ [\[44,48\]](#page-4-0).

Figure 4 shows the low-temperature behavior of the relative TDO frequency shift for a single crystal of $Nb_xBi₂Se₃$ with

FIG. 4. Normalized low-temperature frequency shift $\Delta f(T)$ in a single crystal of $Nb_xBi₂Se₃$ plotted vs reduced temperature T/T_c . Over a wide temperature range, the response is best described with a $T²$ fit (solid line). A fully gapped BCS-like fit (dash-dotted curve) and a BCS-like fit with a free gap parameter (dashed curve) are plotted for comparison.

 H_{rf} | *c* along with several fits. The standard BCS form with the weak-coupling gap value $\Delta_0/T_c = 1.76$, is shown as a black dash-dot line (the fit was carried out to $T_c/3$). It clearly provides an inadequate description of the observed behavior. A BCS fit with a gap ratio Δ_0/T_c as a free parameter (dashed green line) within the same fitting range does not yield an adequate description of the data either. This implies that the data do not represent a fully gapped superconductor with a gap that is significantly smaller than our measurement temperature. The best fit to our data is achieved with a power-law behavior with an exponent $n = 2$.

Low-temperature TDO frequency shift data for $H_{\text{rf}} \parallel ab$ measured on one of the samples is shown in Fig. [5](#page-3-0) as a function of $(T/T_c)^2$ together with data for $H_{\text{rf}} \parallel c$. The total frequency shift in the parallel orientation is very small and the data are correspondingly noisier because in this orientation, the effective filling factor of the TDO sensor coil is much smaller. All data reveal a quadratic low-temperature variation of *λ*. This quadratic temperature dependence is consistent with linearly vanishing point nodes in the gap such as in the axial *p*-wave spin-triplet state as has been reported previously for UBe₁₃ [\[48,49\]](#page-4-0) or $Sr₂RuO₄$ [\[50\]](#page-4-0), or in unconventional gap structures of topological superconductors [\[35\]](#page-4-0) (see below). In contrast, linearly vanishing line nodes, as encountered in the polar *p*-wave state or in *d*-wave superconductors, would yield a linear temperature dependence of *λ*. Since the gap structure of the axial *p*-wave state is anisotropic, different temperature dependences of $\sim T^2$ and $\sim T^4$ are expected, depending

FIG. 5. Normalized low-temperature frequency shift $\Delta f(T)$ in a single crystal (s1, blue) of $Nb_xBi_2Se_3$ with $H_{rf} \parallel c$ and $H_{rf} \parallel ab$, plotted versus reduced temperature T/T_c squared. The dashed line is a quadratic fit of the data. All data sets can be well fitte with a straight line, indicating T^2 behavior in both orientations. An additional sample (s2, gray) also shows a T^2 dependence.

on whether the applied field is parallel or perpendicular to the symmetry axis of the gap [\[48\]](#page-4-0). Furthermore, in an anisotropic material the in-plane penetration depth *λab* and the interlayer penetration depth λ_c are different and could in principle have different T dependencies. Formally, the observation of a T^2 dependence would in our geometry $(H_{rf} || c)$ correspond to an in-plane symmetry axis of the order parameter. However, inhomogeneous order parameter textures and/or inhomogeneous field distributions brought about for example by sample edges lead to a mixture of components such that low-*T* measurements will be dominated by the T^2 term [\[48\]](#page-4-0). This could account for our observation that measurements for $H_{\text{rf}} || c$ and $H_{\text{rf}} || ab$ yield the same T^2 variation. In addition, for $H_{\text{rf}} \parallel c$, the TDO signal arises from in-plane currents that probe λ_{ab} . When H_{rf} || *ab*, the currents have in-plane and out-of-plane components implying that a mixture of both λ_{ab} and λ_c is probed. However, the relative contribution of inter-plane penetration depth is roughly proportional to $(\lambda_c t) / (\lambda_{ab} w)$, where *t* is the thickness of the sample and *w* is its width [\[44\]](#page-4-0). For our samples $t/w \approx 0.2$ and $\lambda_c/\lambda_{ab} \approx 2$ so the signal for both field orientations will be governed by λ_{ab} .

Our observation of point nodes in the gap of $Nb_xBi₂Se₃$ is consistent with recent findings based on specific heat measurements [\[41\]](#page-4-0), which rule out line nodes but could not distinguish between point nodes and a complete gap.

The axial *p*-wave state contains a chirality and thus breaks time-reversal symmetry; however, in the presence of strong spin-orbit coupling, nodal superconducting states that preserve time-reversal symmetry can arise. Their classification [\[35\]](#page-4-0) in the D_{3d} point group, applicable to $Nb_xBi_2Se_3$, reveals that the two-dimensional odd-parity E_u state spontaneously breaks the 3-fold in-plane rotational symmetry leading to a nematic state. This nematic state is characterized by the nematic director marking an in-plane direction of zero total spin. For a director pointing in the k_y direction, an anisotropic fully gapped state with gap minima along k_x arises; whereas for a director along k_x , a nodal state with point nodes along k_y appears. These nodes are symmetry protected owing to the mirror symmetry around the *y* axis [see Fig. $1(b)$]. Thus, our finding of point nodes in the gap in conjunction with the observation of a two-fold in-plane magnetic anisotropy [\[41\]](#page-4-0) identifies the nodal E_u state as the pairing state of $Nb_xBi_2Se_3$.

Strong electron scattering may have profound effects on the temperature dependence of the penetration depth. For instance, impurity scattering can alter the linear *T*-dependence characteristic of line nodes to a quadratic variation as has been discussed for a variety of materials [\[43,51–55\]](#page-4-0). We do not believe that our samples are in the dirty limit, since the observation of quantum oscillations in the Cu homolog [\[56,57\]](#page-4-0) and more recently in the Nb compound [\[46\]](#page-4-0) suggests that these materials have in fact fairly high purity. In addition to the observation of quantum oscillations, the dependence of T_c and of the temperature dependence of λ on defect concentration may serve as another indicator of sample purity. A well-studied example is $BaFe₂(As_{1-x}P_x)₂$ [\[43,55\]](#page-4-0), which has accidental line nodes. The pristine material displays the linear temperature dependence of penetration depth as expected for line nodes, whereas upon the introduction of sufficient irradiation-induced defects *λ* acquires a quadratic temperature dependence. By the time this quadratic temperature dependence emerges, T_c has been significantly suppressed by defect scattering as expected for sign-changing order parameters [\[58,59\]](#page-4-0). In contrast, there is little variation in reported T_c values among $Nb_xBi_2Se_3$ samples, implying that sample-to-sample variations in impurity content are not significant and that the quadratic temperature dependence of *λ* seen here is not caused by strong electron scattering.

In conclusion, we present measurements of the lowtemperature penetration depth of high-quality single crystals of the candidate topological superconductor $Nb_xBi₂Se₃$ $(x = 0.25)$. On multiple samples and for both directions of applied field $(H_{\text{rf}} \parallel c$ and $H_{\text{rf}} \parallel ab)$ we find a quadratic temperature dependence $\Delta\lambda \sim T^2$ indicative of point nodes in the superconducting gap. Our results are consistent with a nematic *Eu* pairing state in which symmetry-protected point nodes appear along the *ky* direction on the Fermi surface. Exploring the origin of the differences between this material and the fully gapped homologs $Cu_xBi₂Se₃$ [\[32\]](#page-4-0) and $Sr_xBi₂Se₃$ [\[38\]](#page-4-0) will be important in understanding the rich physics that arises due to strong spin-orbit coupling.

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